



20Mbps RS-485 Transceivers with ±20kV IEC ESD Protection

FEATURES

- High-Performance and Compliant with RS-485
 TIA/EIA-485 Standard
- 3.0V to 5.5V Supply Voltage
- Bus I/O Protection

 ±20kV HBM ESD
 - ±6kV IEC 6100-4-2 Contact Discharge
- -7V to +12V Common-Mode Input Voltage
- Up to 256 Nodes on the Same Bus (1/8 unit load)
- Low Stand-By Current: <5µA
- Full Fail-safe Guarantees Known Receiver Output State
- Glitch-Free during Power on/Power off
- Short-Circuit Protection
- Over Temperature Protection
- |V_{OD}| >2.1V @ 5V Supply Voltage
- Operating Temperature Range: -40°C to +125°C
- Packages: SOIC-8

DESCRIPTION

The RS1920 is a robust half-duplex RS-485 transceiver for industrial applications. The bus pins are immune to high levels of IEC Contact Discharge ESD events eliminating need of additional system level protection components.

The device operates from a single 3.3V to 5.0V supply.

The RS1920 device can transmit and receive at data rate up to 20Mbps. The wide common-mode voltage range and low input leakage on bus pins make RS1920 suitable for multi-point applications over long cable runs.

The RS1920 is available in industry standard 8-pin SOIC, package for drop-in compatibility. It operates over an ambient temperature range of -40° C to $+125^{\circ}$ C.

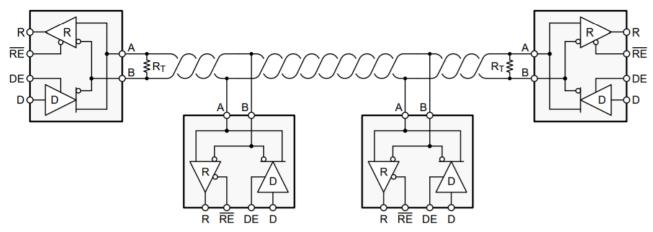
Device Information ⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE(NOM)
RS1920	SOIC-8(SOP8)	4.90mm x 3.90mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

APPLICATIONS

- Electricity Meters (E-Meters)
- Inverters
- HVAC Systems
- Video Surveillance Systems
- Industrial Automation & Control



TYPICAL APPLICATION



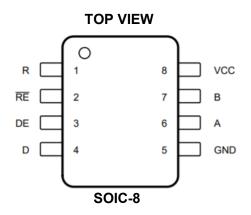
Revision History

Note: Page numbers for previous revisions may different from page numbers in the current version.

VERSION	Change Date	Change Item		
A.0	2022/11/11	Preliminary version completed.		
A.1	2023/06/25	 Update Features description on Page1. Change Parameter description on Page8. 		
A.2	2023/09/21	1、 Update ESD RatingAir Gap Contact on Page5.		



Pin configuration and Functions (Top View)



Pin Description

NAME	PIN	I/O	DESCRIPTION
	SOIC-8		
R	1	0	Receiver Data Output
/RE	2	Ι	Receiver Enable, Active low (with internal pull-up)
DE	3	I	Driver Enable, Active high (with internal pull-down)
D	4	I	Driver Data Input (with internal pull-up)
GND	5	Ground	Ground
А	6	I/O	Bus I/O port, A
В	7	I/O	Bus I/O port, B
VCC	8	Power	Power supply



PACKAGE/ORDERING INFORMATION

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING ^(1/2)	PACKAGE OPTION
RS1920	RS1920XK	-40°C ~+125°C	SOIC-8	RS1920	Tape and Reel,4000

NOTE:

(1) There may be additional marking, which relates to the lot trace code information(data code and vendor code), the logo or the environmental category on the device.

SPECIFICATIONS

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)(2)

SYMBOL		MIN	MAX	UNIT
Vcc	Supply voltage	-0.5	7	V
	Bus A&B voltage	-8	13	V
V _{IO}	Logic input pin (/RE, DE, D)	-0.3	Vcc+0.3	V
	Logic output pin (R)	-0.3	Vcc+0.3	V
TA	Operating temperature	-40	+125	
TJ	Junction temperature		150	°C
T _{stg}	Storage temperature	-65	150	1

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to the GND pin.

ESD Ratings

				VALUE	UNIT
		Human-body model (HBM), per	Bus A &B	±20	kV
	Electrostatic	ANSI/ESDA/JEDEC JS-001	Other pins	±8	kV
$V_{(\text{ESD})}$	discharge	Charge device model (CDM) per JESD22	All pins	±2	kV
		Contact Discharge, per IEC 61000-4-2	Bus A &B	±6	kV
		Air Gap Discharge, per IEC 61000-4-2	Bus A &B	±10	kV

Notes:

1. Per JEDEC document JEP155, 500V HBM allows safe manufacturing of standard ESD control process.

2. Per JEDEC document JEP157, 250V CDM allows safe manufacturing of standard ESD control process.

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

SYMBOL	PARAMETER	МАХ	UNIT	
Vcc	Supply voltage	3.0	5.5	V
VIN	Bus input voltage	-7.0	12	V
VIH	Input high voltage	2.0	Vcc	V
VIL	Input low voltage	0	0.8	V
1/t _{UI}	Data rate		20	Mbps
RL	Differential Load	54		Ω
TA	Operating ambient temperature	-40	125	°C

Thermal Information

		RS1920	
	THERMAL METRIC	SOIC-8	UNIT
		8 PINS	
Reja	Junction-to-ambient thermal resistance	124.7	°C/W
ReJC (top)	Junction-to-case (top) thermal resistance	66.9	°C/W



RS1920

Rejb	Junction-to-board thermal resistance	67.9	°C/W
Ψлт	Junction-to-top characterization parameter	19.2	°C/W
Ψјв	Junction-to-board characterization parameter	67.2	°C/W
ReJC (bot)	Junction-to-case (bottom) thermal resistance	N/A	°C/W



ELECTRICAL CHARACTERISTICS

at $T_A = 25^{\circ}C$, and VCC = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
		R _L = 60 Ω, -7 V ≤ V _{test} ≤ 12	1.5	3.6		
Driver differential output	Vod	R_L = 60 Ω, -7 V ≤ V _{test} ≤ 12, 4.5V ≤ V _{CC} ≤ 5.5V	2.1	3.6		v
voltage magnitude		R _L = 100 Ω, C _L = 50pF	2.0	4.2		
		R _L = 54 Ω, C _L = 50pF	1.5	3.6		
Change in differential output voltage	Δ V _{OD}	R_L = 54 Ω or 100 Ω , C_L = 50pF	-50		50	mV
Common-mode output voltage	Voc	R_L = 54 Ω or 100 Ω , C_L = 50pF	1	Vcc/2	3.3	V
Steady-state commonmode output voltage	$\Delta V_{OC(SS)}$	R_L = 54 Ω or 100 Ω , C_L = 50pF	-50		50	mV
Peak-to-peak commonmode output voltage	$\Delta V_{OC(PP)}$	R_L = 54 Ω or 100 Ω , C_L = 50pF		450		mV
Short-circuit output current	los	$DE = VCC, -7 \; V \le V_O \le 12 \; V$		100	150	mA
Bus input current		DE=0,VCC=0V or 5.5V, VI=12V		75	125	μA
		DE=0,VCC=0V or 5.5V, VI=-7V	-100	-40		μA
Bus input impedance	RI	V _A =-7V, V _B = 12V or V _A =12V, V _B =-7V	96			kΩ
Positive-going input threshold voltage	V _{TH+}			-110	-50	mV
Negative-going input threshold voltage	V _{TH-}		-200	-140		mV
Input hysteresis	V _{HYS}			30		mV
Output high voltage	Vон	I _{ОН} = -4mA	VCC-0.5	VCC- 0.3		V
Output low voltage	V _{OL}	I _{OL} = 4mA		0.2	0.4	V
Output high-impedance current	loz	VO=0V or VCC, /RE =VCC	-1		+1	μA
Output short-circuit current	I _{OSR}	/RE=0, DE=0			95	mA
Input current (D, DE, RE)	lin		-5		+5	μA
		Driver and receiver enabled /RE=0V, DE=VCC, no load		0.95	1.5	mA
		Driver enabled, receiver disabled /RE=VCC, DE=VCC, no load		0.55	1.0	mA
Supply current (quiescent)	Icc	Driver disabled, receiver enabled /RE=0V, DE=0V, no load		0.5	0.9	mA
		Driver and receiver disabled /RE=VCC, DE=0V, no load			5.0	μA

Note:

1. Under any condition, ensure that $V_{\text{TH+}\text{is}}$ at least V_{HYS} higher than $V_{\text{TH-}}$.



SWITCHING CHARACTERISTICS

Over recommended operating conditions

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Driver						
Differential output rise/fall time	t _{r,} t _f	$R_L = 54 \Omega, C_L = 50 pF$		5	12	ns
Propagation delay	t _{PHL} , t _{PLH}	R_L = 54 Ω , C_L = 50pF		12	25	ns
Pulse skew, tphl - tplh	t _{sk(P)}	$R_L = 54 \ \Omega$, $C_L = 50 pF$			3.5	ns
Disable time	t _{PHZ} , t _{PLZ}			10	30	ns
Enchle time	t _{PZH} , t _{PZL}	/RE = 0V		300	800	ns
Enable time	t _{PZH} , t _{PZL}	/RE = VCC		6	12	μs
Receiver						
Differential output rise/fall time	t _{r,} t _f	C∟ = 15pF		4	8	ns
Propagation delay	t _{PHL} , t _{PLH}	C _L = 15pF		40	80	ns
Pulse skew, tphl - tplh	t _{sk(P)}	C∟ = 15pF			12	ns
Disable time	t _{PHZ} , t _{PLZ}			7	20	ns
Enable time	t _{PZH} , t _{PZL}	DE = VCC		30	70	ns
Output high voltage	tpzh, tpzl	DE = 0		6	12	μs

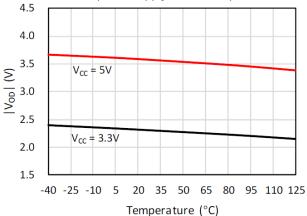
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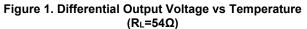
1. CL includes external circuit (fixture and instrumentation etc.) capacitance.



TYPICAL CHARACTERISTICS

At T_A = 25°C, V_{IN} = 5V power supply, Min/Max specs are over recommended operating conditions unless otherwise specified.





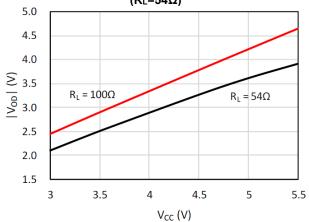


Figure 3. Differential Output Voltage vs Supply Voltage

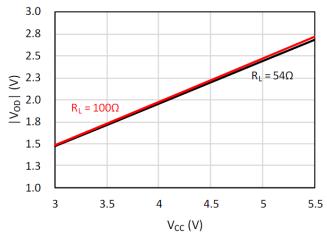


Figure 5. Common Output Voltage vs. Supply voltage

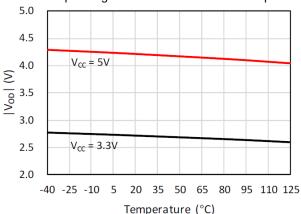


Figure 2. Differential Output Voltage vs Temperature $(R_L=100\Omega)$

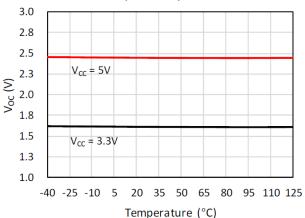
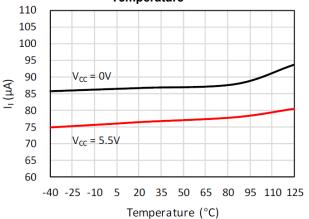


Figure 4. Common-mode Output Voltage vs Temperature

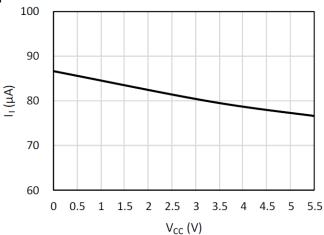


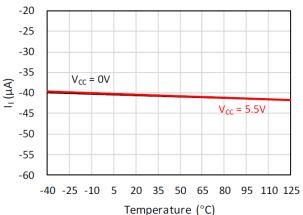




TYPICAL CHARACTERISTICS

At $T_A = 25^{\circ}$ C, $V_{IN}= 5$ V power supply, Min/Max specs are over recommended operating conditions unless otherwise specified







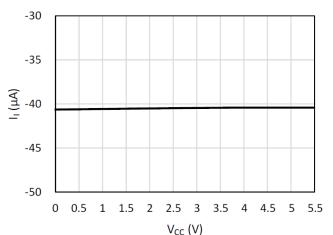


Figure 9. Bus Input Current vs. Supply Voltage, Vi=-7V

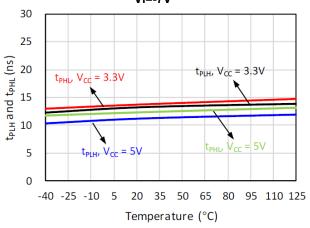


Figure 11. Driver Propagation Delay vs. Temperature

Figure 8. Bus Input Current vs. Temperature, Vi=-7V

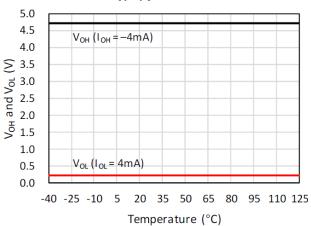


Figure 10. Receiver Output Low vs. Temperature

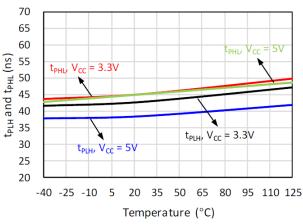
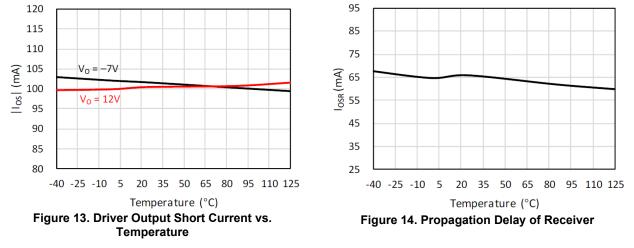


Figure 12. Receiver Propagation Delay vs. Temperature



TYPICAL CHARACTERISTICS

At $T_A = 25^{\circ}$ C, $V_{IN} = 5$ V power supply, Min/Max specs are over recommended operating conditions unless otherwise specified.





Parameter Measurement Information

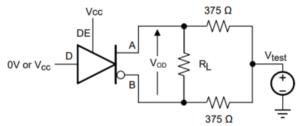
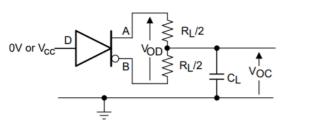


Figure 15 Measurement of Driver Differential Output Voltage With Common-Mode Load



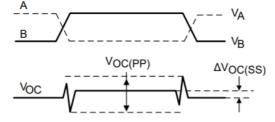
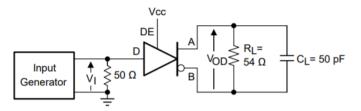


Figure 16 Measurement of Driver Differential and Common-Mode Output With RS-485 Load



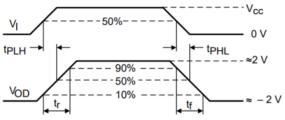
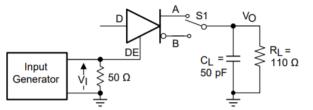


Figure 17 Measurement of Driver Differential Output Rise and Fall Times and Propagation Delays



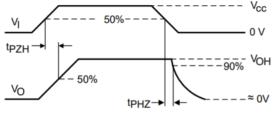
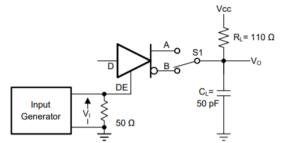


Figure 18 Measurement of Driver Enable and Disable Times With Active High Output and Pull Down Load



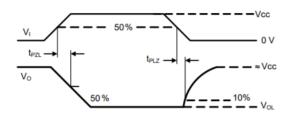


Figure 19 Measurement of Driver Enable and Disable Times With Active Low Output and Pull- Up Load

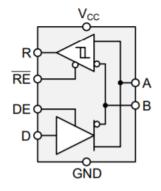


Detailed Description

Overview

The RS1920 s a low-power, half-duplex RS-485 transceiver suitable for data transmission up to 20 Mbps.

Functional Block Diagram



Feature Description

Internal ESD protection circuits protect the transceiver against Electrostatic Discharges (ESD) according to IEC 61000-4-2 of up to ± 6 kV (Contact Discharge), ± 20 kV (Human-body model). The RS1920 provides internal biasing of the receiver input thresholds in combination with large input threshold hysteresis. With a positive input threshold of VIT+ = -50 mV and an input hysteresis of VHYS = 50 mV, the receiver output remains logic high under a bus-idle or bus-short conditions without the need for external failsafe biasing resistors. Device operation is specified over a wide temperature range from -40°C to 125°C.

Device Functional Modes

When the driver enable pin, DE, is logic high, the differential outputs A and B follow the logic states at data input D. A logic high at D causes A to turn high and B to turn low. In this case, the differential output voltage defined as VOD = VA - VB is positive. When D is low, the output states reverse, B turns high, A becomes low, and VOD is negative. When DE is low, both outputs turn high-impedance. In this condition the logic state at D is irrelevant. The DE pin has an internal pull-down resistor to ground, thus when left open the driver is disabled (high-impedance) by default. The D pin has an internal pull-up resistor to VCC, thus, when left open while the driver is enabled, output A turns high and B turns low.

Input	Enable	OutputABHL		Function
D	DE			Function
Н	Н			Actively drive bus high
L	Н	L	Η	Actively drive bus low
Х	L	Ζ	Ζ	Driver disabled
Х	OPEN	Ζ	Ζ	Driver disabled by default
OPEN	Н	Н	L	Actively drive bus high by default

Table 1. Driver Function Table

Note:

X means don't care,

Z means high resistance



When the receiver enable pin, /RE, is logic low, the receiver is enabled. When the differential input voltage defined as $V_{ID} = V_A - V_B$ is positive and higher than the positive input threshold, V_{IT+} , the receiver output, R, turns high. When V_{ID} is negative and lower than the negative input threshold, V_{IT-} , the receiver output, R, turns low. If VID is between V_{IT+} and V_{IT-} the output is indeterminate. When RE is logic high or left open, the receiver output is high-impedance and the magnitude and polarity of V_{ID} are irrelevant. Internal biasing of the receiver inputs causes the output to go failsafe-high when the transceiver is disconnected from the bus (open-circuit), the bus lines are shorted (short-circuit), or the bus is not actively driven (idle bus).

Differential Input	Enable	Output	Function		
$V_{\rm ID} = V_{\rm A} - V_{\rm B}$	/RE	R	Function		
$V_{IT^+}\!< V_{ID}$	L	Н	Receive valid bus high		
$V_{IT-} < V_{ID} < V_{IT+}$	L	Indeterminate	Indeterminate bus state		
$V_{ID} < V_{IT}$	L	L	Receive valid bus low		
X	Н	Ζ	Receiver disabled		
X	OPEN	Ζ	Receiver disabled by default		
Open-circuit bus	L	Н	Fail-safe high output		
Short-circuit bus	L	Н	Fail-safe high output		
Idle(terminated) bus	L	Н	Fail-safe high output		

Table 2. Receiver Function Table

Note:

X means don't care

Z means high resistance

Application Information

The RS1920 is a half-duplex RS-485/RS-422 transceiver commonly used for asynchronous data transmissions. The driver and receiver enable pins allow for the configuration of different operating modes.

Typical Application

An RS-485 bus consists of multiple transceivers connecting in parallel to a bus cable. To eliminate line reflections, each cable end is terminated with a termination resistor, RT, whose value matches the characteristic impedance, Z0, of the cable. This method, known as parallel termination, allows for higher data rates over longer cable length.

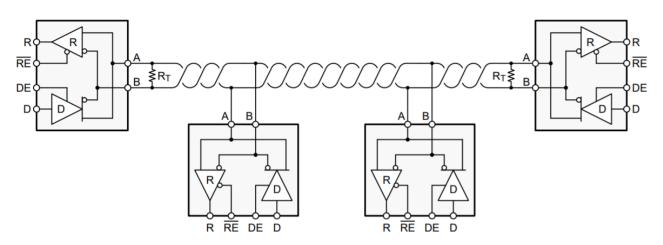


Figure 20. Typical RS-485 Network With Half-Duplex Transceivers



Supply Voltage Design Requirements

In order to ensure the reliability of data transmission and power supply, it is recommended to place decoupling capacitors from 100nF to 220nF as close as possible to the VCC pin of each transceiver.

Layout

Layout Guidelines

Robust and reliable bus node design often requires the use of external transient protection devices in order to protect against surge transients that may occur in industrial environments. Since these transients have a wide frequency bandwidth (from approximately 3 MHz to 300 MHz), high-frequency layout techniques should be applied during PCB design.

1. Place the protection circuitry close to the bus connector to prevent noise transients from propagating across the board.

2. Use VCC and ground planes to provide low inductance. Note that high-frequency currents tend to follow the path of least impedance and not the path of least resistance.

3. Design the protection components into the direction of the signal path. Do not force the transient currents to divert from the signal path to reach the protection device.

4. Apply 100-nF to 220-nF bypass capacitors as close as possible to the VCC pins of transceiver, UART and/or controller ICs on the board.

5. Use at least two vias for VCC and ground connections of bypass capacitors and protection devices to minimize effective via inductance.

6. Use 1-k Ω to 10-k Ω pullup and pulldown resistors for enable lines to limit noise currents in theses lines during transient events.

7. Insert pulse-proof resistors into the A and B bus lines if the TVS clamping voltage is higher than the specified maximum voltage of the transceiver bus pins. These resistors limit the residual clamping current into the transceiver and prevent it from latching up.

8. While pure TVS protection is sufficient for surge transients up to 1 kV, higher transients require metal-oxide varistors (MOVs) which reduce the transients to a few hundred volts of clamping voltage, and transient blocking units (TBUs) that limit transient current to less than 1 mA.

Layout Example

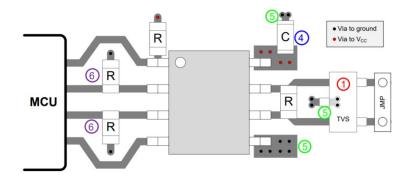
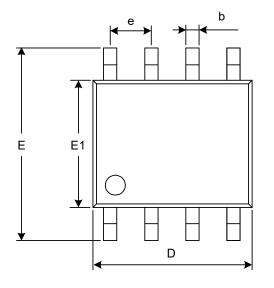
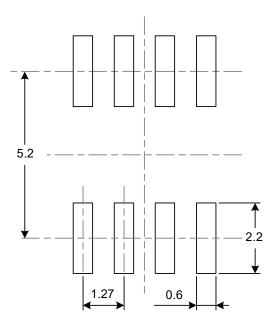


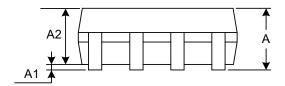
Figure 21. Layout Example

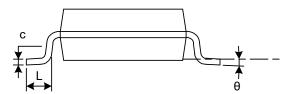
PACKAGE OUTLINE DIMENSIONS SOIC-8





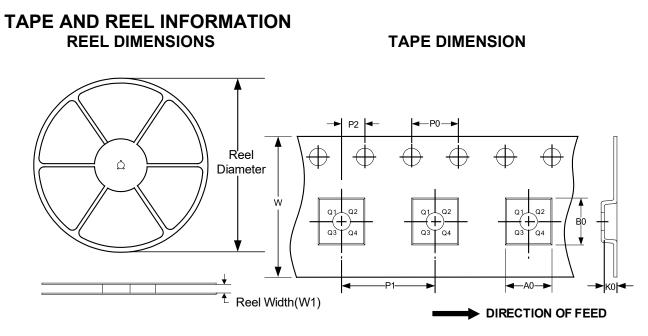
RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions	n Millimeters	Dimensions In Inches			
	Min	Мах	Min	Max		
A	1.350	1.750	0.053	0.069		
A1	0.100	0.250	0.004	0.010		
A2	1.350	1.550	0.053	0.061		
b	0.330	0.510	0.013	0.020		
с	0.170	0.250	0.007	0.010		
D	4.800	5.000	0.189	0.197		
e	1.270	(BSC)	0.050 (BSC)			
E	5.800	6.200	0.228	0.244		
E1	3.800	4.000	0.150	0.157		
L	0.400	1.270	0.016	0.050		
θ	0°	8°	0°	8°		





NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel	Reel Width	A0	B0	K0	P0	P1	P2	W	Pin1
	Diameter	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	Quadrant
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1